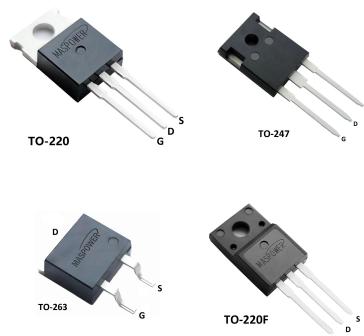


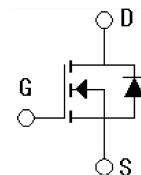
## Features

- Low gate charge
- Low  $C_{rss}$  (typ 13pF)
- Fast switchin
- 100% avalanche tested
- Improved dv/dt capability
- RoHS product



## Applications

- High frequency switching mode power supply
- Electronic ballast based on half bridge
- LED power supplies



## Absolute Ratings ( $T_c=25^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	1000	V
Drain Current-continuous  $I_D$ $T=25^\circ\text{C}$ $T=100^\circ\text{C}$		12	A
		8	A
Drain Current-pulse (note 1)	$I_{DM}$	20*	A
Gate-Source Voltage	$V_{GS}$	$\pm 30$	V
Single pulse avalanche energy (note 2)	$E_{AS}$	160	mJ
Avalanche Current (note 1)	$I_{AR}$	3	A
Repetitive Avalanche Energy(note 1)	$E_{AR}$	90	mJ
Power Dissipation (MS12N100FC/FT)	PD $TC=25^\circ\text{C}$	367	W
	Derate above $25^\circ\text{C}$	2.9	$\text{W}/^\circ\text{C}$
Power Dissipation (MS12N100FE)	PD $TC=25^\circ\text{C}$	100	W
	Derate above $25^\circ\text{C}$	0.8	$\text{W}/^\circ\text{C}$
Power Dissipation (MS12N100FS)	PD $TC=25^\circ\text{C}$	68	W
	Derate above $25^\circ\text{C}$	0.54	$\text{W}/^\circ\text{C}$

Operating and Storage Temperature Range	$T_J, T_{STG}$	-55~+150	°C
Maximum Lead Temperature for Soldering Purposes	$T_L$	300	°C

\*Drain current limited by maximum junction temperature

### Electrical Characteristics( $T_{CASE}=25^\circ C$ unless otherwise specified)

Parameter	Symbol	Tests conditions	Min	Type	Max	Units
Drain-Source Voltage	$BV_{DSS}$	$I_D=250\mu A, V_{GS}=0V$	1000	-	-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=800V, V_{GS}=0V, T_c=25^\circ C$	-	-	1	$\mu A$
		$V_{DS}=720V, T_c=125^\circ C$	-	-	10	$\mu A$
Gate body leakage current	$I_{GSS}$	$V_{DS}=0V, V_{GS}=\pm 30V$	-	-	$\pm 100$	nA

#### On-Characteristics

Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	3.0	-	5.0	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=6A, T_c=25^\circ C$	-	1.0	1.2	$\Omega$
Forward Transconductance	$g_{FS}$	$V_{DS}=40V, I_D=6A$ (note 4)	-	16	-	S

#### Dynamic Characteristics

Input capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V, f=1.0MHz$	-	1584	-	pF
Output capacitance	$C_{oss}$		-	166	-	pF
Reverse transfer capacitance	$C_{rss}$		-	12	-	pF

### Electrical Characteristics( $T_{CASE}=25^\circ C$ unless otherwise specified)

Parameter	Symbol	Tests conditions	Min	Type	Max	Units
<b>Switching-Characteristics</b>						
Turn-On delay time	$t_{d(on)}$	$V_{DD}=600V, I_D=12A, R_{GEN}=25\Omega$ (note 4,5)	-	24	-	ns
Turn-On rise time	$t_r$		-	46	-	ns
Turn-Off delay time	$t_{d(off)}$		-	118	-	ns
Turn-Off rise time	$t_f$		-	58	-	ns
Total Gate Charge	$Q_g$	$V_{DS}=800V, I_D=12A,$	-	41	-	nC

Gate-Source charge	$Q_{gs}$	$V_{GS}=10V$ (note 4,5)	-	9	-	nC
Gate-Drain charge	$Q_{gd}$		-	16	-	nC

### Drain-Source Diode Characteristics and Maximum Ratings

Diode Forward Voltage (note 3)	$V_{SD}$	$V_{GS}=0V, I_S=12A$	-	-	1.2	V
Maximum Pulsed Drain-Source Diode Forward Current	$I_{SM}$	-	-	-	110	A
Maximum Continuous Drain Source Diode Forward Current	$I_S$	-	-	-	12	A
Reverse recovery time	$t_{rr}$	$V_{GS}=0V,$ $I_S=8A \frac{dI_F}{dt}=100A/\mu s$	-	620	-	ns
Reverse recovery charge	$Q_{rr}$	(note 4)	-	4.39	-	$\mu C$

### Thermal Characteristic

Parameter	Symbol	Value			Unit
		MS12N10 0FC/FT	MS12N10 0FE	MS12N100 FS	
Thermal Resistance,junction to Case	$R_{th}(j-C)$	0.4	1.25	1.84	°C/W
Thermal Resistance, Junction to Ambient	$R_{th}(j-A)$	36	62.5	62.5	°C/W

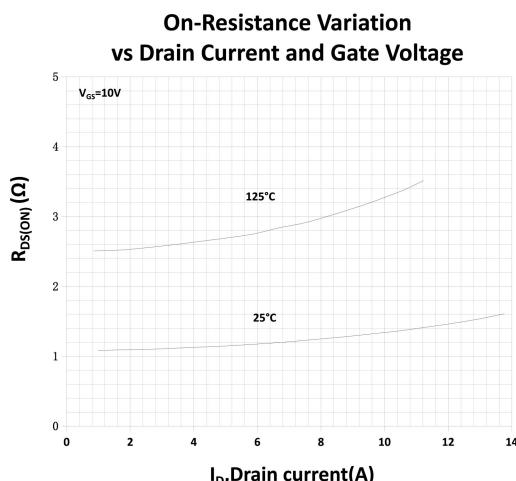
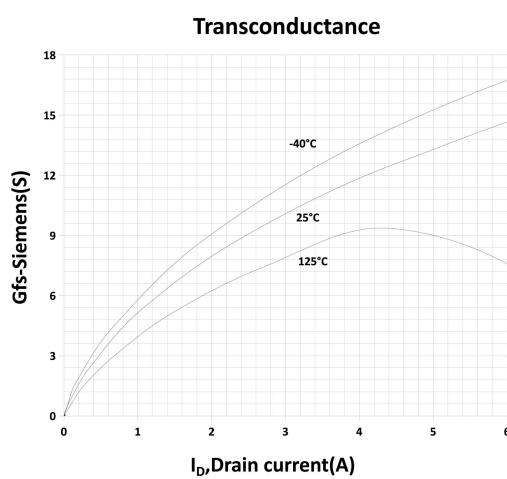
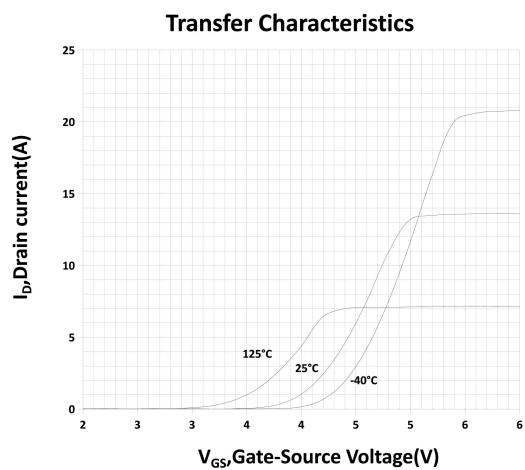
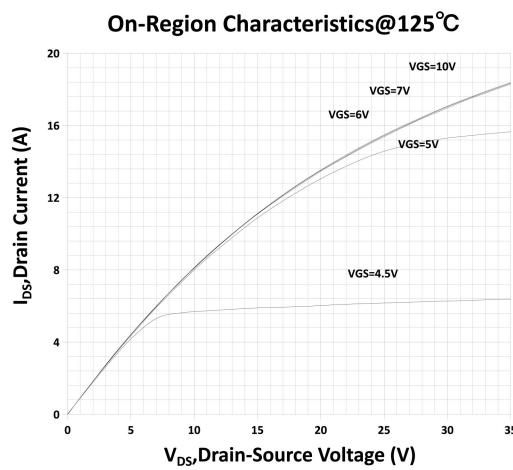
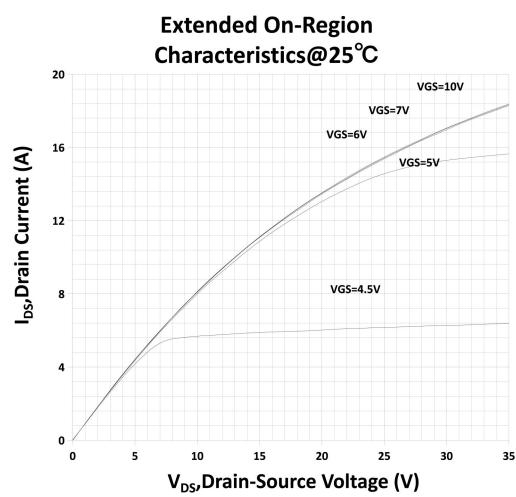
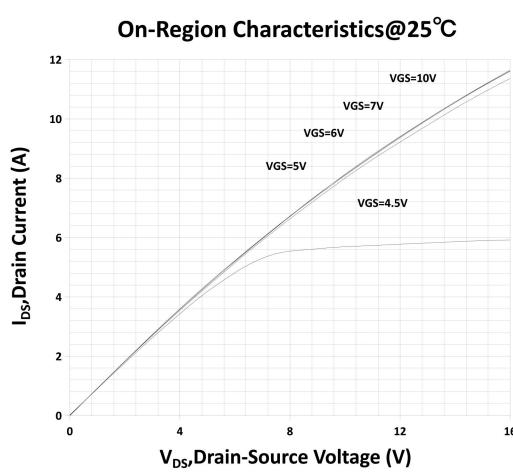
### Order information

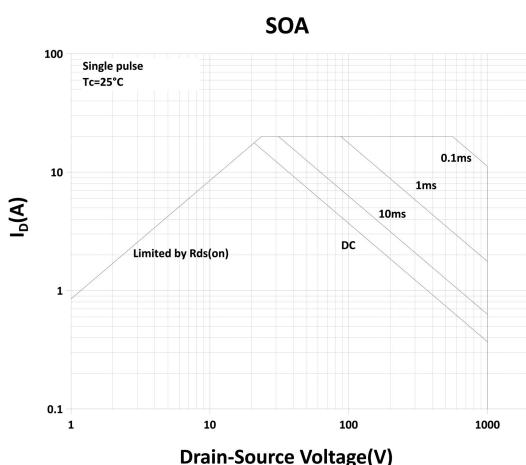
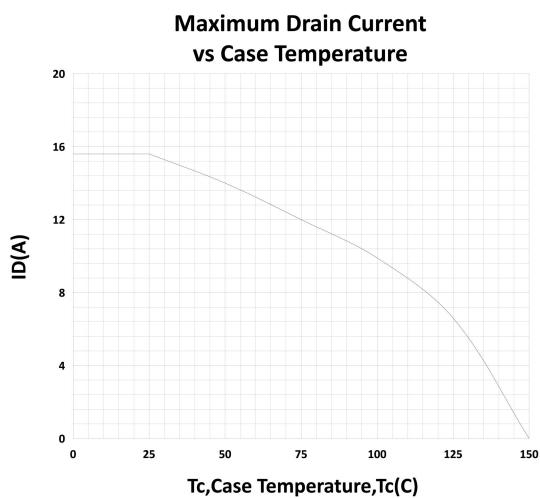
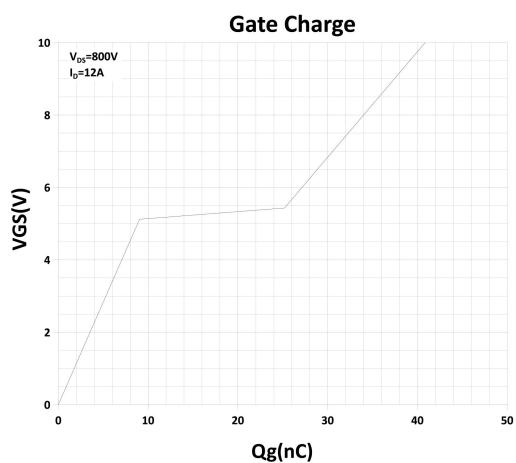
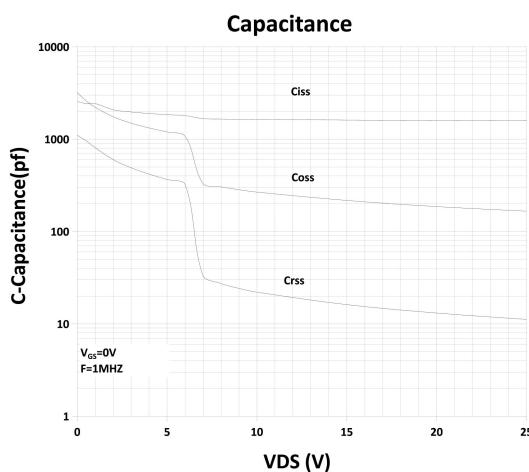
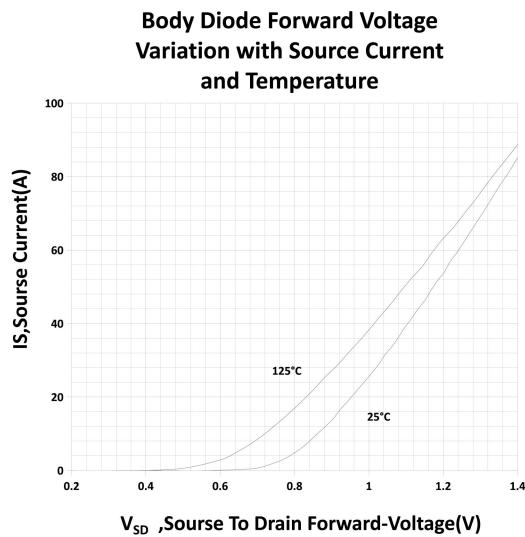
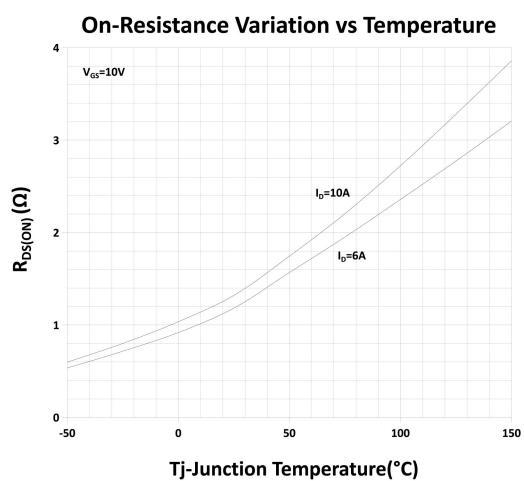
Order codes	Package	Packaging
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MS12N100FE	TO-263	Tube
MS12N100FT	TO-220	Tube
MS12N100FS	TO-220F	Tube

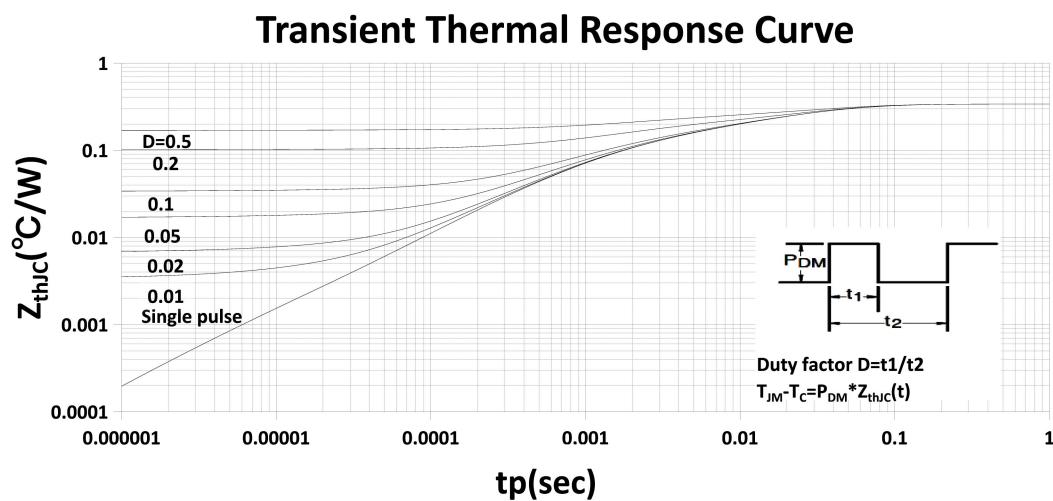
Notes:

1. Pulse width limited by maximum junction temperature
2. L=20mH,  $I_{AS}=12A$ ,  $V_{DD}=50V$ ,  $R_G=25 \Omega$ , Starting  $T_J=25^\circ C$
3.  $I_{SD} \leq 12A, \frac{dI}{dt} \leq 300A/\mu s, V_{DD} \leq BV_{DSS}$ , Starting  $T_J=25^\circ C$
4. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$
5. Essentially independent of operating temperature

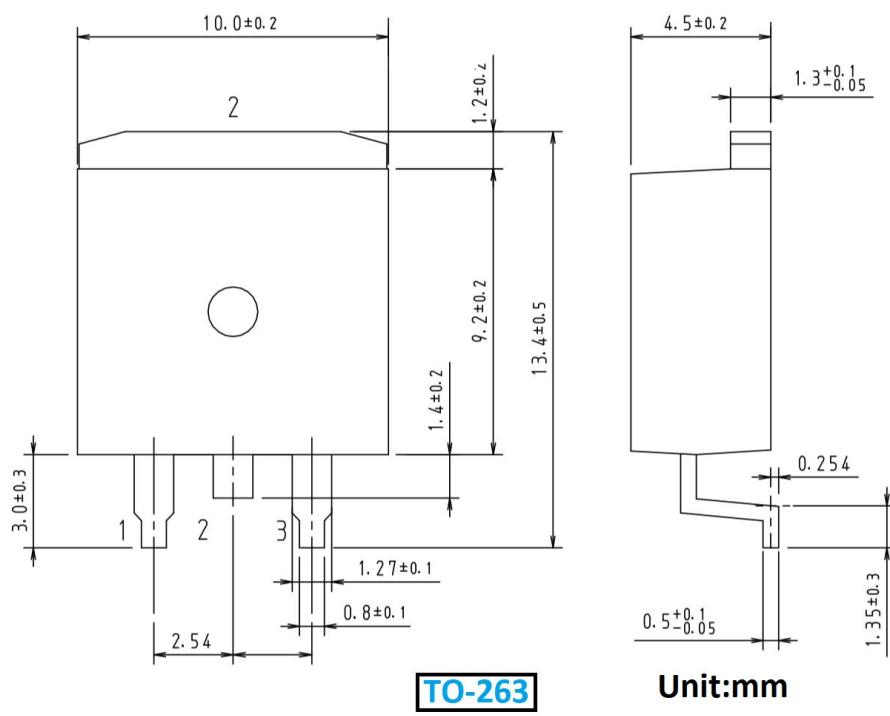
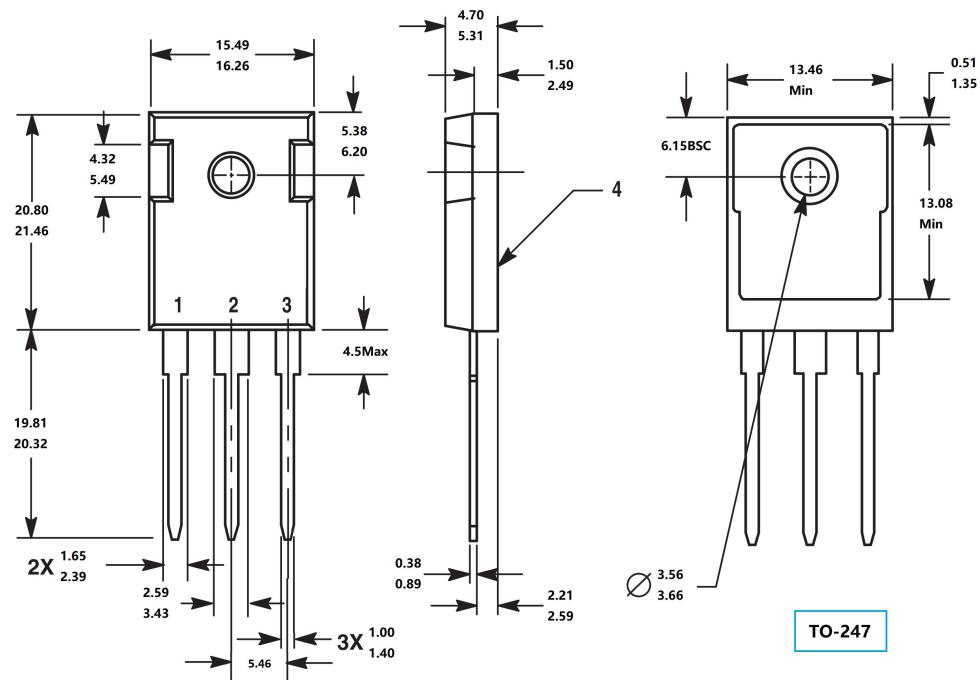
## ELECTRICAL CHARACTERISTICS (curves)



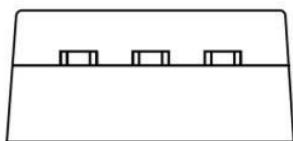
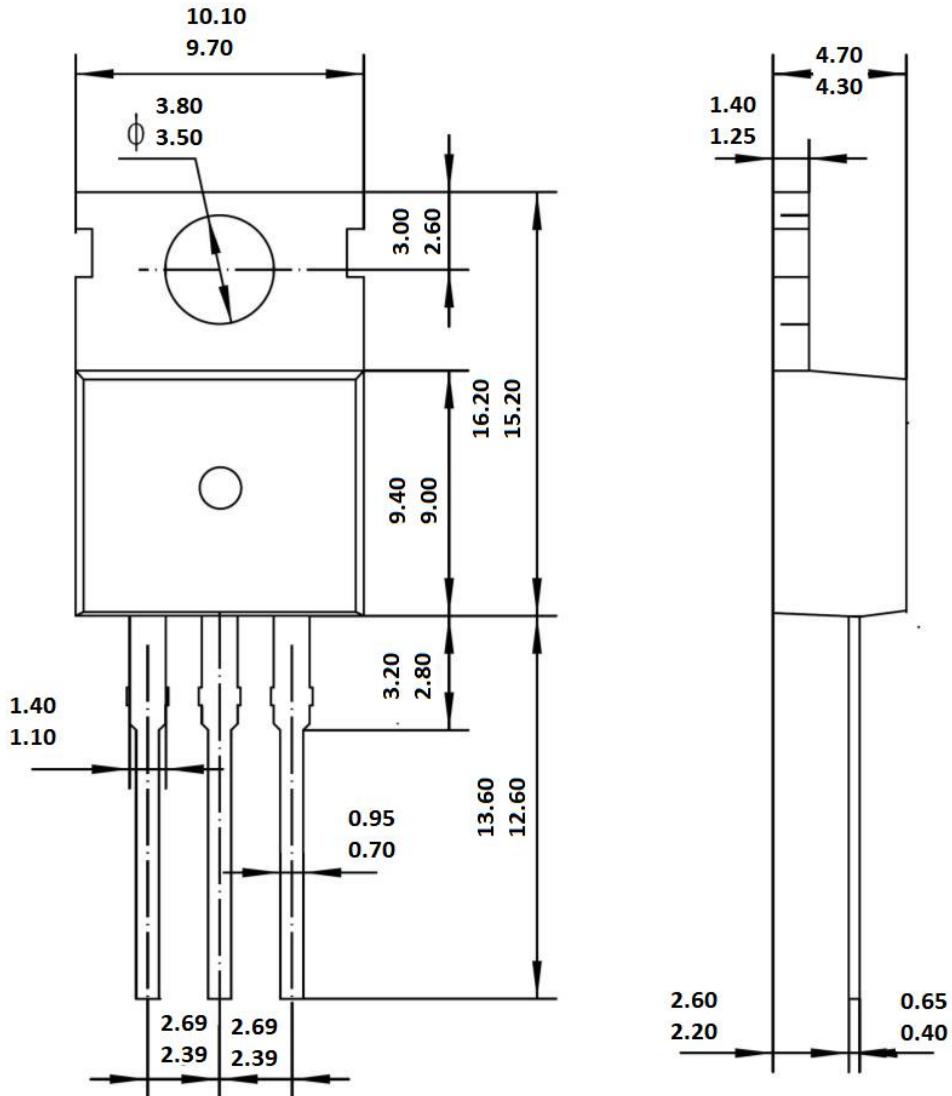




## PACKAGE MECHANICAL DATA



**Unit:mm**



**TO-220**

**Unit: mm**

